# BT151U series C

#### GENERAL DESCRIPTION

Passivated thyristors in a plastic envelope, intended for use in applications requiring high bidirectional blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V <sub>drm</sub> , V <sub>rrm</sub> I <sub>t(av)</sub> I <sub>t(rms)</sub> I <sub>tsm</sub>	BT151U- Repetitive peak off-state voltages Average on-state current RMS on-state current Non-repetitive peak on-state current	<b>500C</b> 500 7.5 12 100	<b>650C</b> 650 7.5 12 100	800C 800 7.5 12 100	V A A A

#### PINNING - SOT533, (I-PAK)

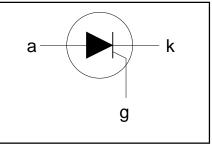
PIN NUMBER	DESCRIPTION
1	cathode
2	anode
3	gate
tab	anode

#### PIN CONFIGURATION

Top view

MRK915

#### SYMBOL



#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
$V_{drm}, V_{rrm}$	Repetitive peak off-state voltages		-	<b>-500C</b> 500 <sup>1</sup>	<b>-650C</b> 650 <sup>1</sup>	<b>-800C</b> 800	v
I <sub>T(AV)</sub> I <sub>T(RMS)</sub> I <sub>TSM</sub>	Average on-state current RMS on-state current Non-repetitive peak on-state current	half sine wave; $T_{mb} \le 104$ °C all conduction angles half sine wave; $T_j = 25$ °C prior to surge	-		7.5 12		A A
l²t dI⊤/dt	I <sup>2</sup> t for fusing Repetitive rate of rise of on-state current after	t = 10 ms t = 8.3 ms t = 10 ms $I_{TM} = 20 \text{ A}; I_G = 50 \text{ mA};$ $dI_G/dt = 50 \text{ mA/}\mu\text{s}$	- - -		100 110 50 50		Α Α Α²s Α/μs
$\begin{matrix} I_{GM} \\ V_{RGM} \\ P_{GM} \\ P_{G(AV)} \\ T_{stg} \\ T_{j} \end{matrix}$	triggering Peak gate current Peak reverse gate voltage Peak gate power Average gate power Storage temperature Junction temperature	over any 20 ms period	- - - -40 -		2 5 0.5 150 125		A > S S C C

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15  $A/\mu s$ .

## BT151U series C

#### THERMAL RESISTANCES

P.   MAX.	
1.3 ) -	K/W K/W K/W
-	70

#### STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

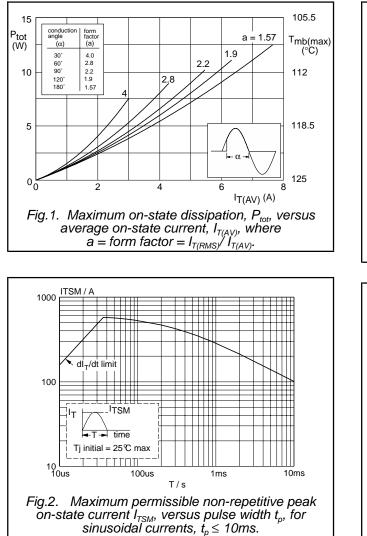
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>GT</sub>	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$	-	2	15	mA
	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	10	40	mA
	Holding current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$	-	7	20	mA
V <sub>τ</sub>	On-state voltage	$I_{T} = 23 \text{ A}$	-	1.44	1.75	V
V <sub>GT</sub>	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$	-	0.6	1.5	V
		$V_{D} = V_{DRM(max)}$ ; $I_{T} = 0.1 \text{ A}$ ; $T_{j} = 125 \text{ °C}$	0.25	0.4	-	V
I <sub>D</sub> , I <sub>R</sub>	Off-state leakage current	$V_D = V_{DRM(max)}^{ORM(max)}; V_R = V_{RRM(max)}; T_j = 125 \degree C$	-	0.1	0.5	mA

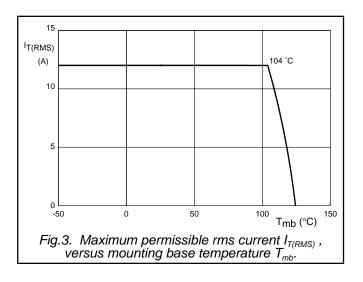
### **DYNAMIC CHARACTERISTICS**

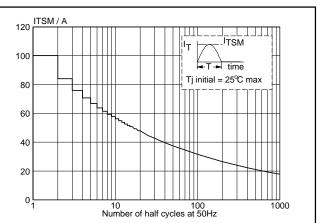
 $T_j = 25$  °C unless otherwise stated

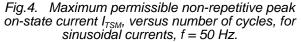
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform				
	, S	Gate open circuit	50	130	-	V/µs
		R <sub>GK</sub> = 100 Ω	200	1000	-	V/µs
t <sub>gt</sub>	Gate controlled turn-on time	$I_{TM} = 40 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A}/\mu \text{s}$	-	2	-	μs
t <sub>q</sub>	Circuit commutated turn-off time	$V_{D} = 67\% V_{DRM(max)}; T_{j} = 125 °C;$ $I_{TM} = 20 A; V_{R} = 25 V; dI_{TM}/dt = 30 A/\mu s;$ $dV_{D}/dt = 50 V/\mu s; R_{GK} = 100 \Omega$	-	70	-	μs

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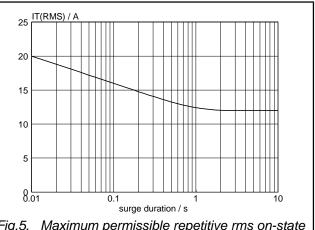
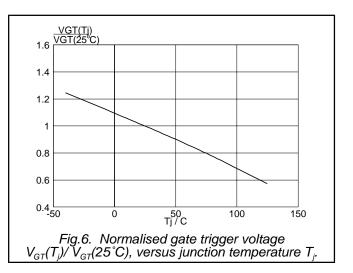
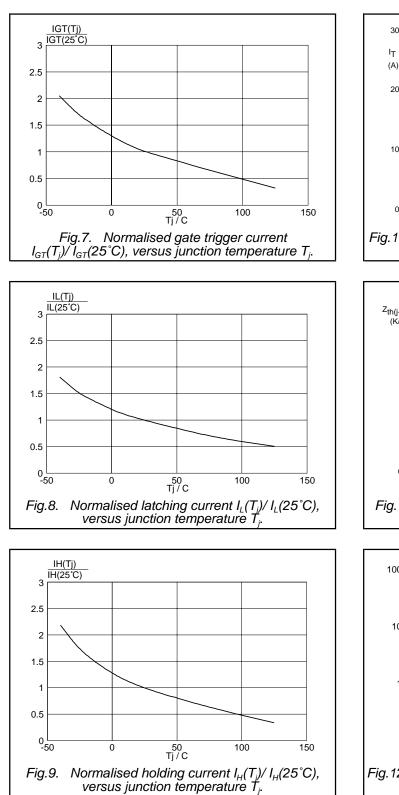


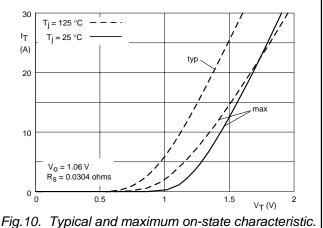
Fig.5. Maximum permissible repetitive rms on-state current  $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz;  $T_{mb} \le 100$  °C.

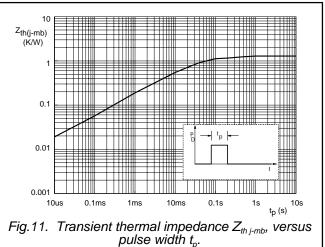


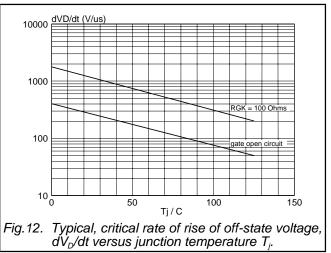
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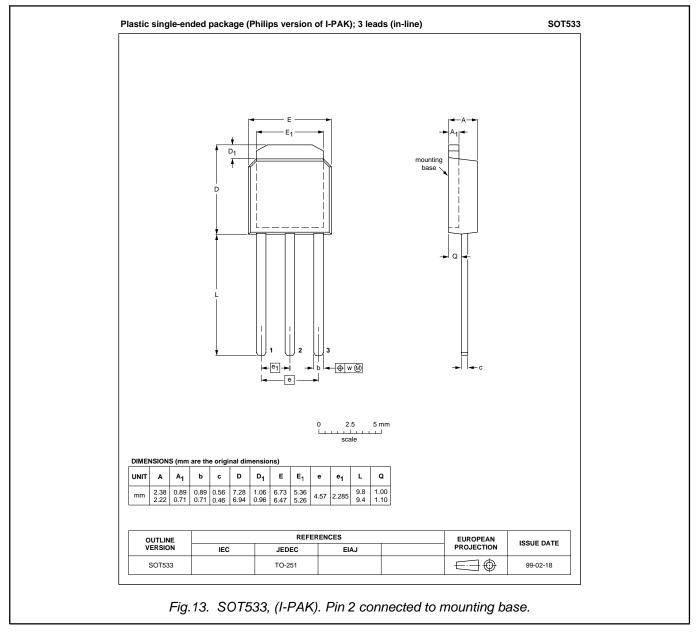






## BT151U series C

#### **MECHANICAL DATA**



## BT151U series C

#### DEFINITIONS

DATA SHEET STATUS					
DATA SHEET STATUS <sup>2</sup>	PRODUCT STATUS <sup>3</sup>	DEFINITIONS			
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice			
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product			
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A			
Limiting values					

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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**<sup>2</sup>** Please consult the most recently issued datasheet before initiating or completing a design.

**<sup>3</sup>** The product status of the device(s) described in this datasheet may have changed since this datasheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.